



GLF1220H, GLF1221H

Nano Current Leakage I_QSmart™ Load Switch with Slew Rate Control and Reverse Current Blocking

Product Specification

DESCRIPTION

The GLF1220H / GLF1221H is an advanced technology fully integrated I_QSmart™ load switch device with reverse current blocking (RCB) protection and slew rate control of the output voltage.

The GLF1220H / GLF1221H offers industry leading reverse current blocking (RCB) protection performance, featuring an ultra-low threshold voltage. The GLF1220H / GLF1221H minimizes reverse current flow in the event that the V_{OUT} voltage exceeds the V_{IN} voltage.

The GLF1220H / GLF1221H load switch device supports an industry leading wide input voltage range that helps to improve system operating life and overall performance. One GLF120x device can be used in multiple voltage rail applications which helps mitigate inventory management and reduces BOM cost.

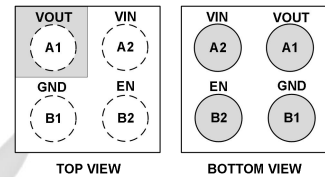
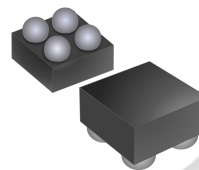
FEATURES

- Wide Input Range, V_{IN}: 1.5 V to 5.5 V
6 V_{ABS} Max
- I_{OUT} Max: 1 A
- Low R_{ON}: 52 mΩ Typ. at 5.5 V_{IN}
- Ultra-Low I_Q: 500 nA Typ at 5.5 V_{IN}
- Ultra-Low I_{SD}: 10 nA Typ at 5.5 V_{IN}
- Reverse Current Blocking Protection
- Integrated Output Discharge Switch, GLF1221H
- Internal Pull-Down Resistor on EN Pin

APPLICATIONS

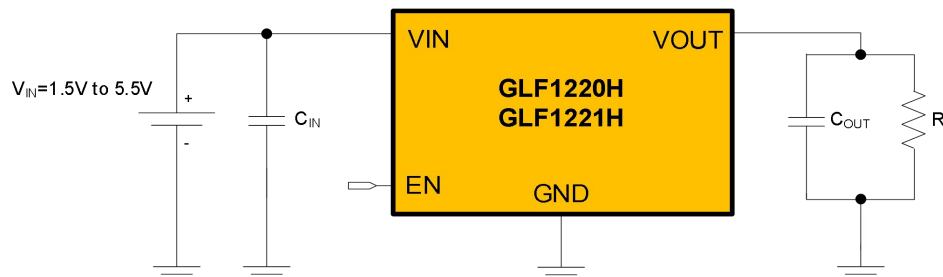
- Smart IoT Devices
- Portable Industrial Devices
- Low Power Subsystems
- Wearable Devices

PACKAGE



0.67 mm x 0.67 mm x 0.425 mm
0.35 mm Pitch WL-CSP

APPLICATION DIAGRAM



ALTERNATE DEVICE OPTIONS

Part Number	Top Mark	R _{ON} (Typ) at V _{IN(MAX)}	Reverse Current Blocking	V _{out} Rise Time at 3.3 V _{IN}	Output Discharge	EN Activity
GLF1220H	Z	52 mΩ	Yes	390 μs	NA	High
GLF1221H	R				85 Ω	

FUNCTIONAL BLOCK DIAGRAM

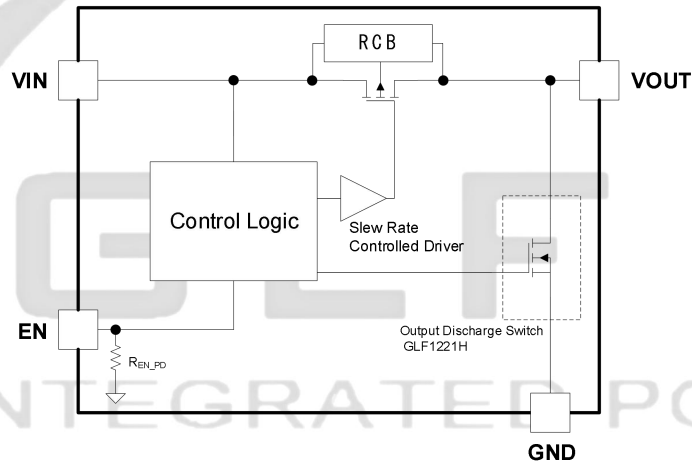
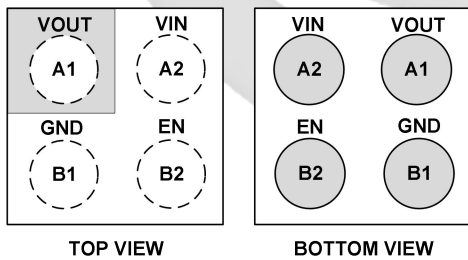


Figure 1. Functional Block Diagram

PIN CONFIGURATION

PIN DEFINITION



Pin #	Name	Description
A1	VOUT	Switch Output
A2	VIN	Switch Input. Supply Voltage for IC
B1	GND	Ground
B2	EN	Enable to control the switch. The EN pin has an internal pull-down resistor.

Figure 2. 0.67 mm x 0.67 mm x 0.425 mm WLCSP

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V _{IN} , V _{OUT} , V _{EN}	Each Pin Voltage Range to GND	- 0.3	6	V
I _{OUT}	Maximum Continuous Switch Current		1	A
	Pulse, 300 us pulse and 2 % duty cycle		2	
P _D	Power Dissipation at T _A = 25 °C		1	W
T _{STG}	Storage Junction Temperature	- 65	150	°C
T _A	Operating Temperature Range	- 40	85	°C
θ _{JA}	Thermal Resistance, Junction to Ambient (board dependent)		125	°C/W
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	± 3	kV
		Charged Device Model, JESD22-C101	± 2	

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V _{IN}	Supply Voltage	1.5	5.5	V
T _A	Ambient Operating Temperature	- 40	+ 85	°C

ELECTRICAL CHARACTERISTICS

Values are at $V_{IN} = 3.3\text{ V}$ and $T_A = 25\text{ °C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Basic Operation						
V_{IN}	Supply Voltage		1.5		5.5	V
$I_Q^{(1)}$	Quiescent Current	$V_{IN} = 5.5\text{ V}, V_{EN} = 0\text{ V}, I_{OUT} = 0\text{ mA}$		500	680	
		$V_{IN} = 5.5\text{ V}, V_{EN} = 0\text{ V}, I_{OUT} = 0\text{ mA}, T_A = 85\text{ °C}^{(4)}$		550		
I_{SD}	Shutdown Current	EN = Disable, $I_{OUT} = 0\text{ mA}, V_{IN} = 1.5\text{ V}$		1		nA
		EN = Disable, $I_{OUT} = 0\text{ mA}, V_{IN} = 2.5\text{ V}$		2		
		EN = Disable, $I_{OUT} = 0\text{ mA}, V_{IN} = 3.3\text{ V}$		3		
		EN = Disable, $I_{OUT} = 0\text{ mA}, V_{IN} = 4.5\text{ V}$		4		
		EN = Disable, $I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}$		10	40	
		EN = Disable, $I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}, T_A = 55\text{ °C}^{(4)}$		50		
		EN = Disable, $I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}, T_A = 85\text{ °C}^{(4)}$		275		
R_{ON}	On-Resistance	$V_{IN} = 5.5\text{ V}, I_{OUT} = 500\text{ mA}$	$T_A = 25\text{ °C}$	52	60	mΩ
			$T_A = 85\text{ °C}^{(4)}$	60		
		$V_{IN} = 4.5\text{ V}, I_{OUT} = 500\text{ mA}$	$T_A = 25\text{ °C}$	57	65	
			$T_A = 85\text{ °C}^{(4)}$	67		
		$V_{IN} = 3.3\text{ V}, I_{OUT} = 500\text{ mA}$	$T_A = 25\text{ °C}$	67	77	
			$T_A = 85\text{ °C}^{(4)}$	79		
		$V_{IN} = 2.5\text{ V}, I_{OUT} = 300\text{ mA}$	$T_A = 25\text{ °C}$	82		
		$V_{IN} = 1.8\text{ V}, I_{OUT} = 300\text{ mA}$	$T_A = 25\text{ °C}$	112		
$V_{IN} = 1.5\text{ V}, I_{OUT} = 100\text{ mA}$	$T_A = 25\text{ °C}$	142				
R_{DSC}	Output Discharge Resistance	$V_{EN} = \text{Low}, I_{FORCE} = 10\text{ mA}, \text{GLF1221H Only}$		85		Ω
V_{IH}	EN Input Logic High Voltage	$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$	1.2			V
V_{IL}	EN Input Logic Low Voltage	$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$			0.3	V
R_{EN}	EN Internal resistance	Internal Pull-down Resistance		10		MΩ
I_{EN}	EN Current ⁽²⁾	$V_{EN} = 5.5\text{ V}$		0.55	0.8	μA
V_{RCB_TH}	RCB Protection Threshold	$V_{OUT} - V_{IN}$		40		mV
V_{RCB_RL}	RCB Protection Release	$V_{IN} - V_{OUT}$		30		
Switching Characteristics ⁽²⁾						
t_{dON}	Turn-On Delay	$R_L = 150\text{ Ω}, C_{OUT} = 0.1\text{ μF}$		290		μs
t_R	V_{OUT} Rise Time			390		
t_{dOFF}	Turn-Off Delay ^{(3), (4)}	$R_L = 150\text{ Ω}, C_{OUT} = 0.1\text{ μF}$ GLF1220H		16		
t_F	V_{OUT} Fall Time ^{(3), (4)}			30		
t_{dOFF}	Turn-Off Delay ^{(3), (4)}	$R_L = 150\text{ Ω}, C_{OUT} = 0.1\text{ μF}$ GLF1221H		16		
t_F	V_{OUT} Fall Time ^{(3), (4)}			11		

- Notes:
- I_Q does not include the enable pull down current (I_{EN}) through the pull-down resistor R_{EN} .
 - $t_{ON} = t_{dON} + t_R, t_{OFF} = t_{dOFF} + t_F$
 - Output discharge path is enabled during off.
 - By design; characterized, not production tested.

TIMING DIAGRAM

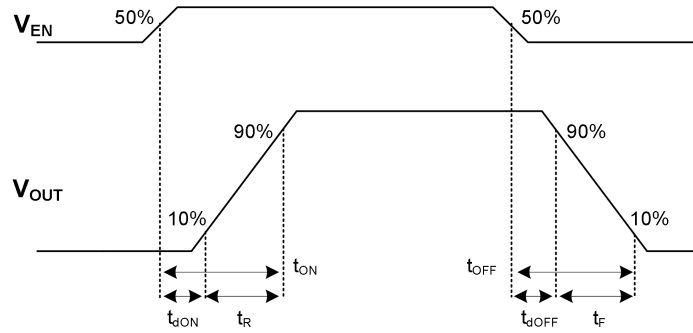


Figure 3. Timing Diagram

TYPICAL PERFORMANCE CHARACTERISTICS

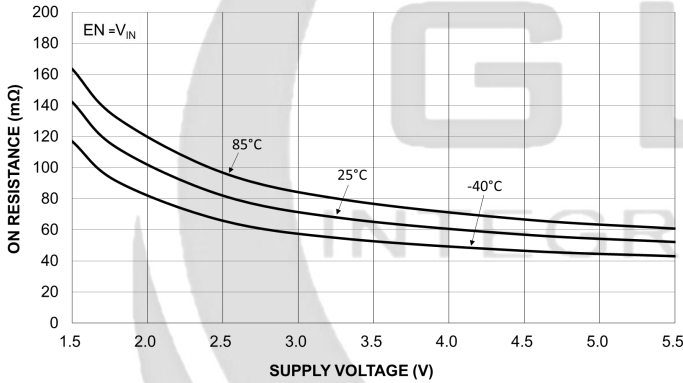


Figure 4. On-Resistance vs. Supply Voltage

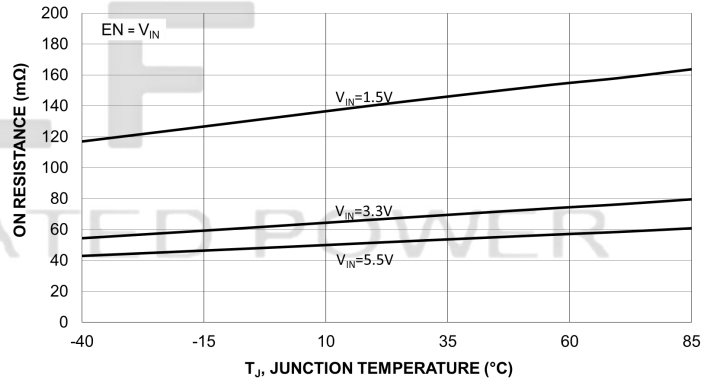


Figure 5. On-Resistance vs. Temperature

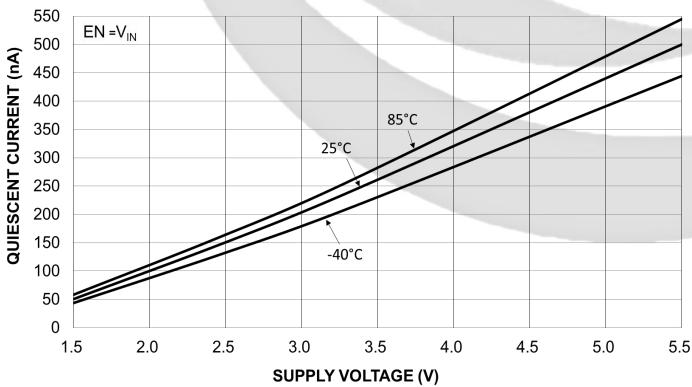


Figure 6. Quiescent Current vs. Supply Voltage

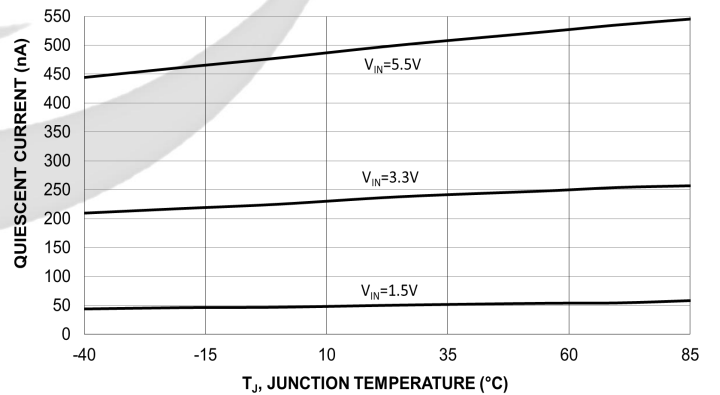


Figure 7. Quiescent Current vs. Temperature

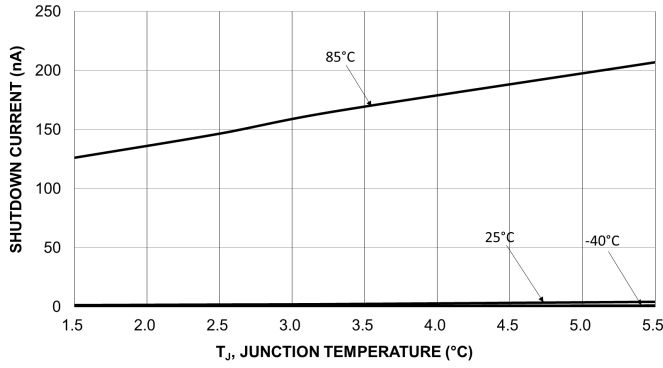


Figure 8. Shutdown Current vs. Supply Voltage

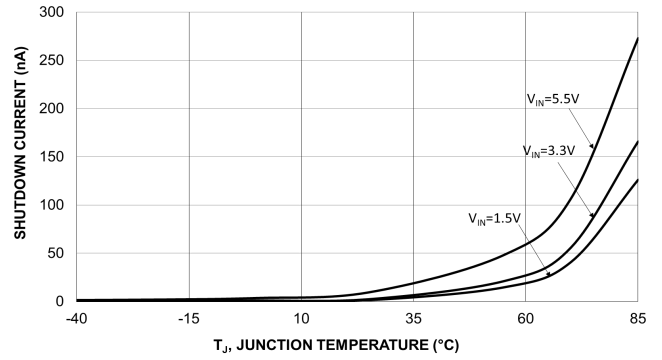


Figure 9. Shutdown Current vs. Temperature

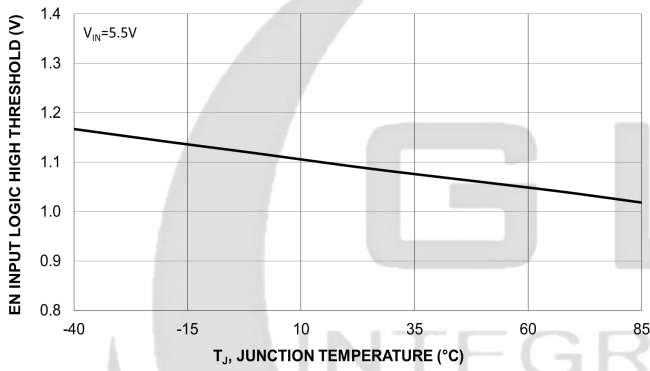


Figure 10. EN Input Logic High Threshold vs. Temperature

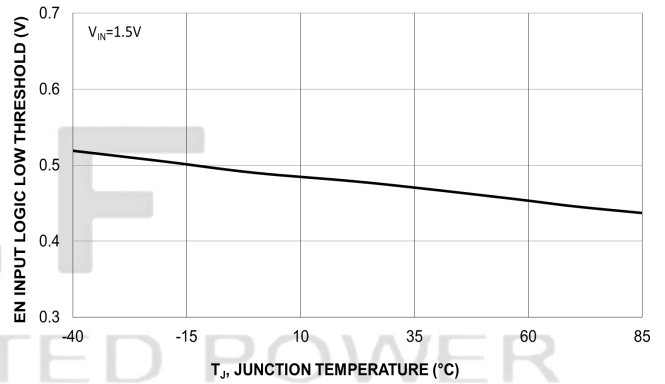


Figure 11. EN Input Logic Low Threshold vs. Temperature

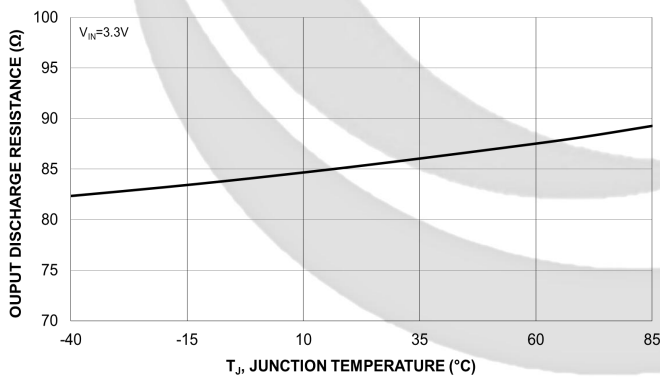


Figure 12. Output Discharge Resistance vs. Temperature
GLF1221H

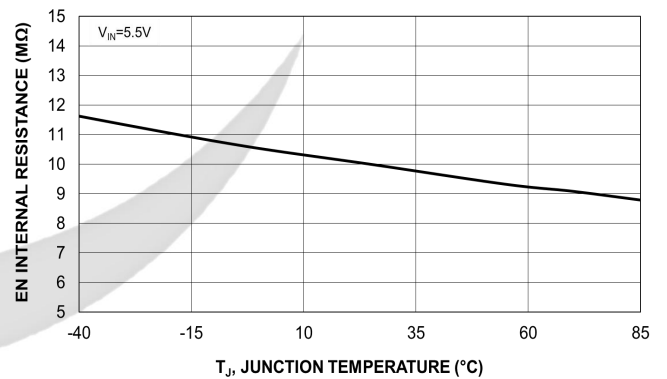


Figure 13. EN Internal Resistance vs. Temperature

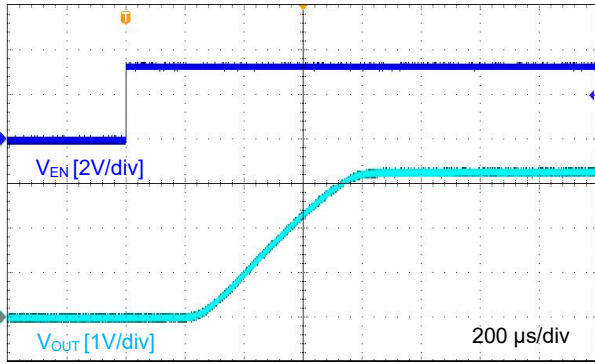


Figure 14. Turn-On Response, GLF1220H
 $V_{IN}=3.3\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

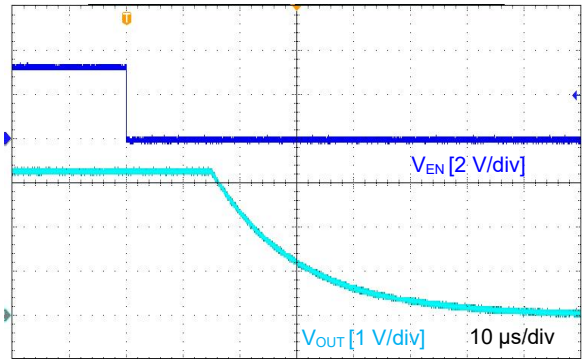


Figure 15. Turn-Off Response, GLF1220H
 $V_{IN}=3.3\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

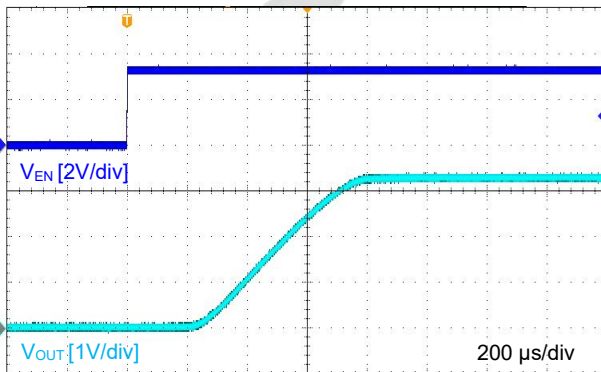


Figure 16. Turn-On Response, GLF1221H
 $V_{IN}=3.3\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

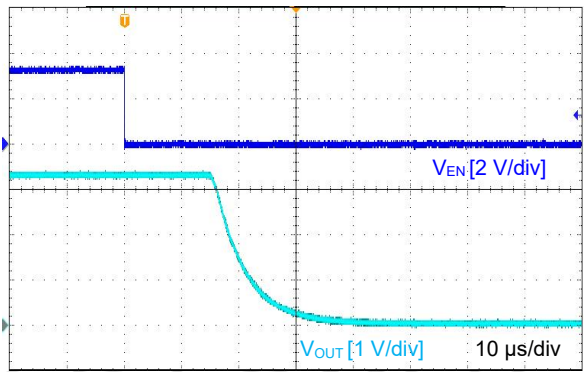


Figure 17. Turn-Off Response, GLF1221H
 $V_{IN}=3.3\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

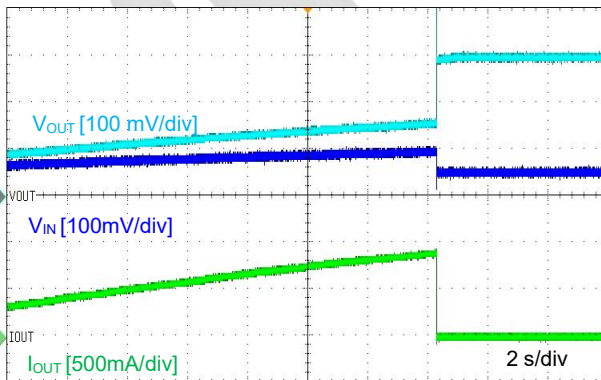


Figure 18. Reverse Current Blocking Threshold
 $V_{IN}=3.3\text{ V}$, $V_{OUT}=\text{Up to }3.4\text{ V}$, $C_{IN}=0.1\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$

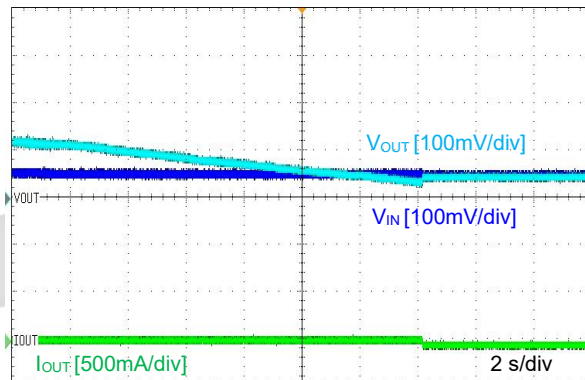


Figure 19. Reverse Current Blocking Release
 $V_{IN}=3.3\text{ V}$, $V_{OUT}=\text{Down to }3.2\text{ V}$, $C_{IN}=0.1\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$

APPLICATION INFORMATION

The GLF1220H and GLF1221H are integrated 1 A, ultra-low I_QSmart™ load switch devices with a fixed slew rate control to limit the inrush current during turn on. Each device is capable of operating over a wide input range from 1.5 V to 5.5 V with very low on-resistance to reduce conduction loss. In the off state, these devices consume very low leakage current to avoid unwanted standby current and save limited input power. The package is a 0.67 mm x 0.67 mm x 0.425 mm wafer level chip scale package, saving space in compact applications. It is constructed using 4 bumps, with a 0.35 mm pitch for manufacturability.

Input Capacitor

The GLF1220H and GLF1221H do not require an input capacitor. However, to reduce the voltage drop on the input power rail caused by transient inrush current at start-up, a 0.1 μF capacitor is recommended to be placed close to the VIN pin. A higher input capacitor value can be used to further attenuate the input voltage drop.

Output Capacitor

The GLF1220H and GLF1221H do not require an output capacitor. However, use of an output capacitor is recommended to mitigate voltage undershoot on the output pin when the switch is turning off. Undershoot can be caused by parasitic inductance from board traces or intentional load inductances. If load inductances do exist, use of an output capacitor can improve output voltage stability and system reliability. The C_{OUT} capacitor should be spaced close to the VOUT and GND pins.

EN Pin

The GLF1220H and GLF1221H can be activated by forcing EN pin high level. Note that the EN pin has an internal pull-down resistor to help pull the main switch to a known “off state” when no EN signal is applied from an external controller.

Reverse Current Blocking

The GLF1220H and GLF1221H have a built-in reverse current blocking protection which always monitors the output voltage level regardless of the status of EN pin to check if it is greater than the input voltage. When the output voltage goes beyond the input voltage by the reverse current blocking protection threshold voltage (V_{RCB_TH}), the reverse current blocking function block turns off the switch. Note that some reverse current can occur until the V_{RCB_TH} is triggered. The main switch will resume normal operation when the output voltage drops below the input source by the reverse current blocking protection release voltage (V_{RCB_RL}).

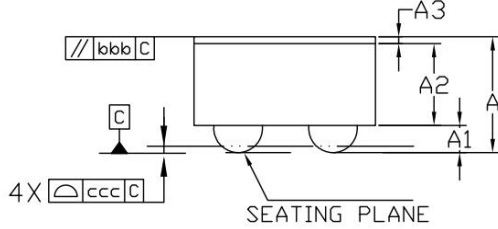
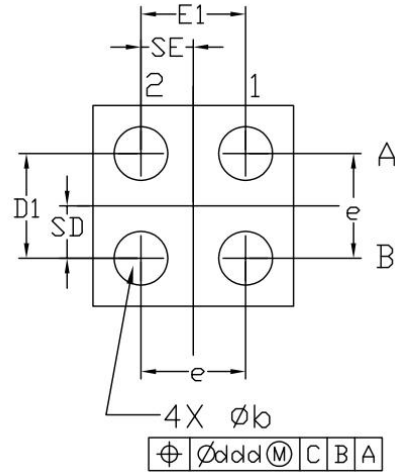
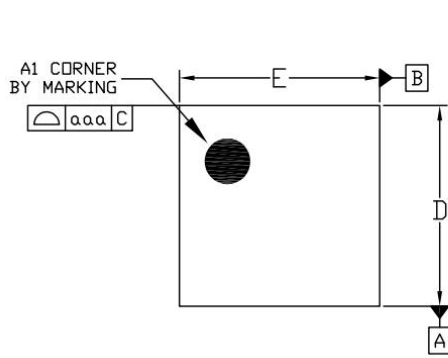
Output Discharge Function

The GLF1221H has an internal discharge N-channel FET switch on the VOUT pin. When EN signal turns the main power FET to an off state, the N-channel switch turns on to discharge an output capacitor quickly.

Board Layout

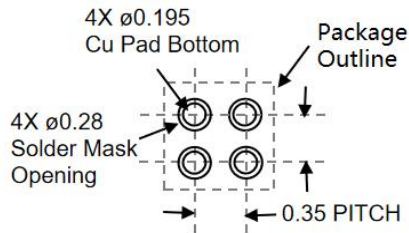
All traces should be as short as possible to minimize parasitic inductance effects. Wide traces for VIN, VOUT, and GND will help reduce signal degradation and parasitic effects during dynamic operation as well as improve the thermal performance at high load current.

PACKAGE OUTLINE



Dimensional Ref.			
REF.	Min.	Nom.	Max.
A	0.380	0.425	0.470
A1	0.085	0.100	0.115
A2	0.275	0.300	0.325
A3	0.020	0.025	0.030
D	0.655	0.670	0.685
E	0.655	0.670	0.685
D1	0.300	0.350	0.400
E1	0.300	0.350	0.400
b	0.145	0.180	0.215
e	0.350 BSC		
SD	0.175 BSC		
SE	0.175 BSC		
Tol. of Form&Position			
aaa	0.10		
bbb	0.10		
ccc	0.05		
ddd	0.05		

Recommended Footprint

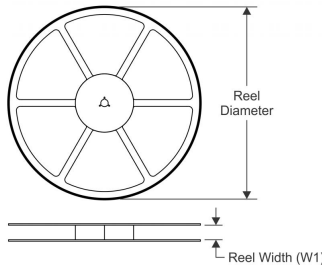


Notes

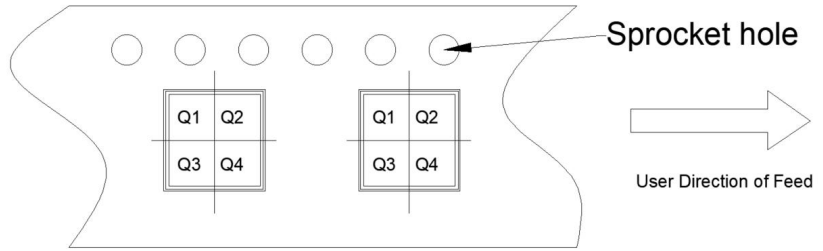
1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES)
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
3. A3: BACKSIDE LAMINATION

TAPE AND REEL INFORMATION

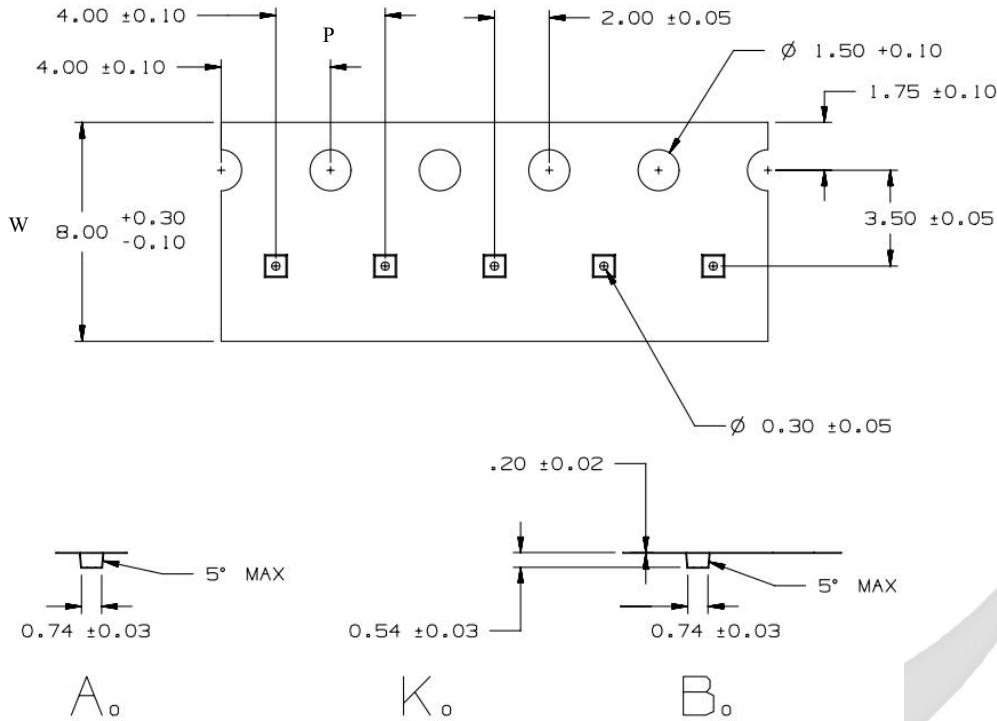
REEL DIMENSIONS



QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE



TAPE DIMENSIONS



Device	Package	Pins	SPQ	Reel Diameter (mm)	Reel Width W1	A0	B0	K0	P	W	Pin1
GLF1220H	WLCSP	4	4000	180	9	0.74	0.74	0.54	4	8	Q1
GLF1221H	WLCSP	4	4000	180	9	0.85	0.85	0.59	4	8	Q1

Remark:

- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P1: Pitch between successive cavity centers

SPECIFICATION DEFINITIONS

Document Type	Meaning	Product Status
Target Specification	This is a target specification intended to support exploration and discussion of critical needs for a proposed or target device. Parameters including the typical, minimum, and maximum values are desired, or target. GLF reserves the right to change contents at any time without warning or notification. A target specification will not guarantee the future production of the device.	Design / Development
Preliminary Specification	This is a draft version of a product specification which is under internal review and subject to change. GLF reserves the right to change the specification at any time without warning or notification. A preliminary specification will not guarantee the future production of the device.	Qualification
Product Specification	This document represents the characteristics of the device.	Production

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